



MT53B512M32D2DS-053 AAT:E

Part Number: MT53B512M32D2DS-053 AAT:E
 Manufacturer/Brand: Micron Technology
 Product description: IC DRAM 16G 1866MHZ FBGA
 Datasheets:
 Ship From: Hong Kong
 Shipment Way: DHL/Fedex/TNT/UPS/EMS



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Image may be representation. See specifications for product details.

Specifications of MT53B512M32D2DS-053 AAT:E

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|--------------------------------|--|
| PART NUMBER | MT53B512M32D2DS-053 AAT:E |
| MANUFACTURER | Micron Technology |
| DESCRIPTION | IC DRAM 16G 1866MHZ FBGA |
| LEAD FREE STATUS / ROHS STATUS | |
| DATA SHEET | |
| WRITE CYCLE TIME - WORD, PAGE | - |
| VOLTAGE - SUPPLY | 1.1V |
| TECHNOLOGY | SDRAM - Mobile LPDDR4 |
| SERIES | - |
| OTHER NAMES | MT53B512M32D2DS-053 AAT:E-ND MT53B512M32D2DS-053AAT:E |
| OPERATING TEMPERATURE | -40°C ~ 105°C (TA) |
| MEMORY TYPE | Volatile |
| MEMORY SIZE | 16Gb (512M x 32) |
| MEMORY INTERFACE | - |
| MEMORY FORMAT | DRAM |
| LEAD FREE STATUS | Lead free |
| DETAILED DESCRIPTION | SDRAM - Mobile LPDDR4 Memory IC 16Gb (512M x 32) 1866MHz |
| CLOCK FREQUENCY | 1866MHz |

Related Tags

| | | |
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